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NTE7141
Integrated Circuit
Dual BIMOS Operational Amplifier
w/MOSFET Input, Bipolar Output

Description:

The NTE7141 is a dual, operational amplifier in an 8-Lead Mini-DIP type package that combines the advantages of MOS and bipolar transistors on the same monolithic chip. The gate-protected MOSFET (PMOS) input transistors provide high input impedance and a wide common-mode input voltage range (typically to 0.5V below the negative supply rail). The bipolar output transistors allow a wide output voltage swing and provide a high output current capability.

Features:

- Internally Compensated
- MOSFET Input Stage:
 - Very High Input Impedance
 - Very Low Input Current
 - Wide Common-Mode Input Voltage Range
 - Rugged Input Stage – Bipolar Diode Protected
- Directly Replaces Industry Type 1458 in Most Applications
- Operation From 4V-to-36V Single or Dual Supplies
- Characterized for $\pm 15V$ Operation for TTL Supply Systems with Operation down to 4V
- Wide Bandwidth
- High Voltage-Follower Slew Rate
- Output Swings to Within 0.5V of Negative Supply at $V+ = 5V$, $V- = 0$

Applications:

- Ground-Referenced Single-Supply Amplifiers in Automobile and Portable Instrumentation
- Sample and Hold Amplifiers
- Long-Duration Timers/Multivibrators (Microseconds – Minutes – Hours)
- Photocurrent Instrumentation
- Active Filters
- Intrusion Alarm Systems
- Comparators
- Instrumentation Amplifiers
- Function Generators
- Power Supplies

Absolute Maximum Ratings:

DC Supply Voltage (Between V+ and V– Terminals)	36V
Operating Voltage Range	4 to 36V or ± 2 to $\pm 18V$
Differential-Mode Input Voltage	$\pm 8V$
Common-Mode DC Input Voltage	(V+ +8V) to (V– –0.5V)
Input-Terminal Current	1mA
Device Dissipation, P_D	630mW
Derate Linearly Above $+55^{\circ}C$	6.67mW/ $^{\circ}C$
Operating Temperature Range, T_{opr}	–40° to +85°C
Storage Temperature Range, T_{stg}	–65° to +150°C
Lead Temperature (During Soldering, 1/16" from case, 10sec max), T_L	+265°C
Output Short-Circuit Duration (Note 1)	Unlimited

Note 1. Short circuit may be applied to GND or to either supply. Temperature and/or supply voltages must be limited to keep dissipation within maximum rating.

Electrical Characteristics: (V+ = +15V, V– = –15V unless otherwise specified)

Parameter	Symbol	Test Conditions		Min	Typ	Max	Unit
Input Offset Voltage	$ V_{iol} $	$T_A = +25^{\circ}C$		–	5	15	mV
		$T_A = -40^{\circ}$ to $+85^{\circ}C$		–	10	–	mV
Input Offset Current	$ I_{iol} $	$T_A = +25^{\circ}C$		–	0.5	30	pA
		$T_A = +85^{\circ}C$		–	32	–	pA
Input Current	I_I	$T_A = +25^{\circ}C$		–	10	50	pA
		$T_A = +85^{\circ}C$		–	640	–	pA
Large-Signal Voltage Gain	A_{OL}	Note 2	$T_A = +25^{\circ}C$	20k	100k	–	V/V
				86	100	–	dB
			$T_A = -40^{\circ}$ to $+85^{\circ}C$	–	63k	–	V/V
				–	96	–	dB
Common-Mode Rejection Ratio	CMRR	$T_A = +25^{\circ}C$	–	32	320	$\mu V/V$	
			70	90	–	dB	
		$T_A = -40^{\circ}$ to $+85^{\circ}C$	–	32	–	$\mu V/V$	
			–	90	–	dB	
Common-Mode Input-Voltage Range	V_{ICR}	$T_A = +25^{\circ}C$		–15	–15.5 to +12.5	+11	V
		$T_A = -40^{\circ}$ to $+85^{\circ}C$		–	–15 to +12.3	–	V
Power Supply Rejection Ratio	$\Delta V_{IO}/\Delta V$	$T_A = +25^{\circ}C$		–	100	150	$\mu V/V$
	PSSR			76	80	–	dB
	$\Delta V_{IO}/\Delta V$	$T_A = -40^{\circ}$ to $+85^{\circ}C$		–	150	–	$\mu V/V$
	PSSR			–	76	–	dB

Note 2. $V_O = 26V_{P-P}$, +12V, –14V and $R_L = 2k\Omega$.

Electrical Characteristics (Cont'd): ($V_+ = +15V$, $V_- = -15V$ unless otherwise specified)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Maximum Output Voltage	V_{OM+}	$T_A = +25^\circ C$, $R_L = 2k\Omega$	+12	+13	—	V
	V_{OM-}		-14	-14.4	—	V
	V_{OM+}	$T_A = +25^\circ C$, Note 3	0.4	0.13	—	V
	V_{OM-}	$T_A = -40^\circ$ to $+85^\circ C$, $R_L = 2k\Omega$	—	+12.4	—	V
	V_{OM-}		—	-14.2	—	V
Supply Current, For Both Amps	I_+	$T_A = +25^\circ C$	—	8	12	mA
		$T_A = -40^\circ$ to $+85^\circ C$	—	8.4	—	mA
Total Device Dissipation	P_D	$T_A = +25^\circ C$	—	240	360	mW
		$T_A = -40^\circ$ to $+85^\circ C$	—	252	—	mW
Temperature Coefficient of Input Offset Voltage	$\Delta V_{IO}/\Delta T$	$T_A = -40^\circ$ to $+85^\circ C$	—	15	—	$\mu A^\circ C$
Input Resistance	R_I	$T_A = +25^\circ C$	—	1.5	—	$T\Omega$
Input Capacitance	C_I	$T_A = +25^\circ C$	—	4	—	pF
Output Resistance	R_O	$T_A = +25^\circ C$	—	60	—	Ω
Equivalent Wideband Input Noise Voltage	e_n	$T_A = +25^\circ C$, $R_S = 100\Omega$	$f = 1kHz$	40	—	nV/\sqrt{Hz}
			$f = 10kHz$	12	—	nV/\sqrt{Hz}
Short-Circuit Current to Opposite Supply Source	I_{OM+}	$T_A = +25^\circ C$	—	40	—	mA
Sink	I_{OM-}		—	11	—	mA
Gain-Bandwidth Product	f_T	$T_A = +25^\circ C$	—	4.5	—	MHz
Slew Rate	SR	$T_A = +25^\circ C$	—	9	—	$V/\mu s$
Transient Response: Rise Time	t_r	$T_A = +25^\circ C$, $R_L = 2k\Omega$, $C_L = 100pF$	—	0.08	—	μs
Overshoot			—	10	—	%
Setting Time at $10V_{P-P}$ 1mV	t_s	$T_A = +25^\circ C$, $R_L = 2k\Omega$, $C_L = 100pF$, Voltage Follower	—	4.5	—	μs
10mV			—	1.4	—	μs
Crosstalk	CT	$T_A = +25^\circ C$, $f = 1kHz$	—	120	—	dB

Note 3. $V_+ = 5V$, $V_- = GND$, $I_{Sink} = 200\mu A$.

Electrical Characteristics: ($T_A = +25^\circ C$, $V_+ = +5V$, $V_- = -5V$ unless otherwise specified)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Input Offset Voltage	$ V_{IO} $		—	5	—	mV
Input Offset Current	$ I_{IO} $		—	0.1	—	pA
Input Current	I_I		—	2	—	pA
Input Resistance	R_I		—	1	—	$T\Omega$
Large-Signal Voltage Gain	A_{OL}		—	100k	—	V/V
			—	100	—	dB
Common-Mode Rejection Ratio	$CMRR$		—	32	320	$\mu V/V$
			70	90	—	dB

Electrical Characteristics (Cont'd): ($T_A = +25^\circ\text{C}$, $V+ = +5\text{V}$, $V- = -5\text{V}$ unless otherwise specified)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Common-Mode Input-Voltage Range	V_{ICR}		—	-0.5	—	V
			—	+2.6	—	V
Power Supply Rejection Ratio	$\Delta V_{IO}/\Delta V$		—	31.6	—	$\mu\text{V/V}$
	PSSR		—	90	—	dB
Maximum Output Voltage	V_{OM+}		—	3.0	—	V
	V_{OM-}		—	0.3	—	V
Maximum Output Current: Source	I_{OM+}		—	20	—	mA
	Sink		—	1	—	mA
Slew Rate	SR		—	7	—	$\text{V}/\mu\text{s}$
Gain-Bandwidth Product	f_T		—	4.5	—	MHz
Supply Current	I_+		—	4	—	mA
Device Dissipation	P_D		—	20	—	mW

Pin Connection Diagram

